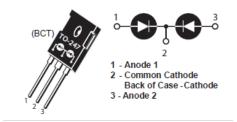


MSC050SDA070BCT Zero Recovery Silicon Carbide Schottky Dual Diode

Product Overview

The silicon carbide (SiC) power Schottky barrier diodes (SBD) product line from Microsemi increases your performance over silicon diode solutions while lowering your total cost of ownership for high-voltage applications. The MSC050SDA070BCT is a 700 V, 50 A SiC dual common cathode SBD in a three-lead TO-247 package shown below.



Features

The following are key features of the MSC050SDA070BCT device:

- No reverse recovery
- · Low forward voltage
- · Low leakage current
- · Avalanche energy rated
- RoHS compliant

Benefits

The following are benefits of the MSC050SDA070BCT device:

- · High switching frequency
- Low switching losses
- Low noise (EMI) switching
- · Higher reliability systems
- · Increased system power density

Applications

The MSC050SDA070BCT device is designed for the following applications:

- Power factor correction (PFC)
- Anti-parallel diode
 - Switch-mode power supply
 - Inverters/converters
 - Motor controllers
- · Freewheeling diode
 - Switch-mode power supply
 - Inverters/converters
- · Snubber/clamp diode



Electrical Specifications

This section shows the specifications for the MSC050SDA070BCT device. All ratings are per leg.

Absolute Maximum Ratings

The following table shows the absolute maximum ratings for the MSC050SDA070BCT device.

All ratings: $T_C = 25$ °C unless otherwise specified.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
V _R	Maximum DC reverse voltage	700	V
V _{RRM}	Maximum peak repetitive reverse voltage	700	
V _{RWM}	Maximum working peak reverse voltage	700	
I _F	Maximum DC forward current (T _c = 25 °C)	88	А
	Maximum DC forward current (T _c = 135 °C)	39	
	Maximum DC forward current (T _c = 145 °C)	32	
I _{FRM}	Repetitive peak forward surge current ($T_c = 25 ^{\circ}\text{C}$, $t_p = 8.3 \text{ms}$, half sine wave)		
I _{FSM}	Non-repetitive forward surge current ($T_c = 25$ °C, $t_p = 8.3$ ms, half sine wave)	124	
P _{tot}	Power dissipation (T _c = 25 °C)	283	W
	Power dissipation (T _c = 110 °C)	123	
T _J , T _{STG}	Operating and storage temperature range	-55 to 175	°C
T _L	Lead temperature for 10 seconds	300	
E _{AS}	Single-pulse avalanche energy (starting T_J = 25 °C, L = 0.08 mH, peak I_L = 50 A)	100	mJ

The following table shows the thermal and mechanical characteristics of the MSC050SDA70BCT device.

Table 2 • Thermal and Mechanical Characteristics

Symbol	Characteristic	Min	Тур	Max	Unit
R _{θJC}	Junction-to-case thermal resistance		0.37	0.53	°C/W
W _T	Package weight		0.22		OZ



Symbol	Characteristic	Min	Тур	Max	Unit
			5.9		g
	Mounting torque, 6-32 or M3 screw			10	lbf-in
				1.1	N-m

Electrical Performance

The following table shows the static characteristics of the MSC050SDA070BCT device.

Table 3 • Static Characteristics

Symbol	Characteristic	Test Conditions	Тур	Max	Unit
V _F	Forward voltage	I _F = 50 A, T _J = 25 °C	1.5	1.8	V
		I _F = 50 A, T _J = 175 °C	1.9		
I _{RM}	Reverse leakage current	V _R = 700 V, T _J = 25 °C	15	200	μΑ
		V _R = 700 V, T _J = 175 °C	250		
Q _C	Total capacitive charge	V _R = 400 V, T _J = 25 °C	133		nC
С	Junction capacitance	$V_R = 1 \text{ V, T}_J = 25 \text{ °C, } f = 1 \text{ MHz}$	2034		pF
	Junction capacitance	V _R = 200 V, T _J = 25 °C, f = 1 MHz	248		
	Junction capacitance	$V_R = 400 \text{ V, } T_J = 25 \text{ °C, } f = 1 \text{ MHz}$	216		



Performance Curves

This section shows the typical performance curves for the MSC050SDA070BCT device.

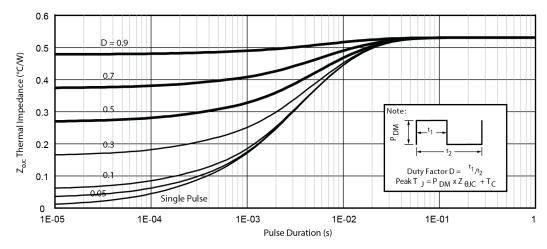


Figure 1 • Maximum Transient Thermal Impedance

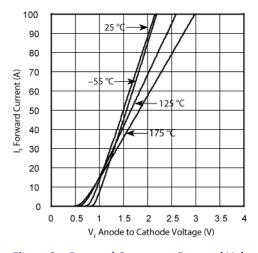


Figure 2 • Forward Current vs Forward Voltage

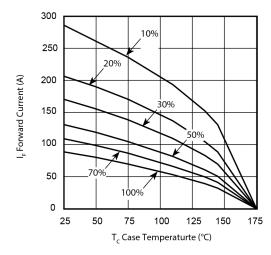


Figure 3 • Max Forward Current vs Case Temp



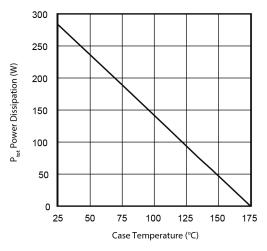


Figure 4 • Max Power Dissipation vs Case Temp

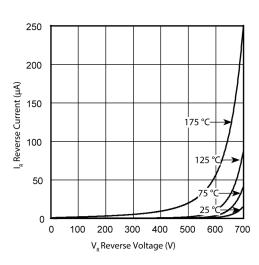


Figure 5 • Reverse Current vs. Reverse Voltage

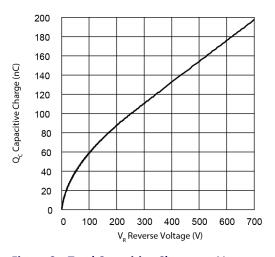


Figure 6 ● Total Capacitive Charge vs. V_R

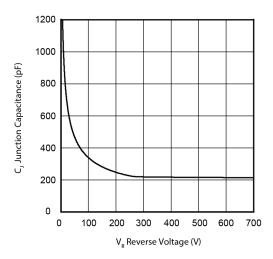


Figure 7 • Junction Capacitance vs V_R



Package Specification

This section outlines the package specification for the MSC050SDA070BCT device.

Package Outline Drawing

This section shows the TO-247 package drawing of the MSC050SDA070BCT device. Dimensions are in millimeters and (inches).

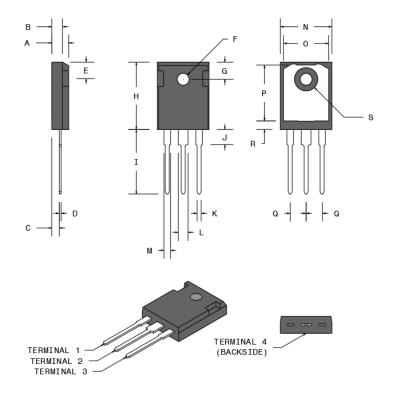


Figure 8 • Package Outline Drawing

The following table shows the TO-247 dimensions and should be used in conjunction with the package outline drawing.

Table 4 • Dimensions

Symbol	Min. (mm)	Max. (mm)	Min. (in.)	Max (in.)
A	4.69	5.31	0.185	0.209
В	1.49	2.49	0.059	0.098
С	2.21	2.59	0.087	0.102
D	0.40	0.79	0.016	0.031
Е	5.38	6.20	0.212	0.244
F	3.50	3.81	0.138	0.150



Symbol	Min. (mm)	Max. (mm)	Min. (in.)	Max (in.)
G	6.15 BSC		0.242 BSC	
Н	20.80	21.46	0.819	0.845
I	19.81	20.32	0.780	0.800
J	4.00	4.50	0.157	0.177
К	1.01	1.40	0.040	0.055
L	2.87	3.12	0.113	0.123
M	1.65	2.13	0.065	0.084
N	15.49	16.26	0.610	0.640
0	13.50	14.50	0.531	0.571
Р	16.50	17.50	0.650	0.689
Q	5.45 BSC		0.215 BSC	
R	2.00	2.75	0.079	0.108
S	7.10	7.50	0.280	0.295
Terminal 1	Anode 1			
Terminal 2	Common cathode			
Terminal 3	Anode 2			
Terminal 4	Common cathode			





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